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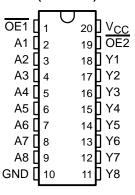
- Inputs Are TTL-Voltage Compatible
- EPIC[™] (Enhanced-Performance Implanted CMOS) Process
- High Latch-Up Immunity Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

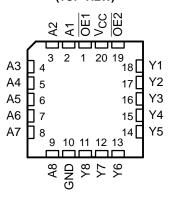
The 'AHCT540 octal buffers/drivers are ideal for driving bus lines or buffer memory address registers. These devices feature inputs and outputs on opposite sides of the package to facilitate printed-circuit-board layout.

The 3-state control gate is a two-input AND gate with active-low inputs so that if either output-enable (OE1 or OE2) input is high, all corresponding outputs are in the high-impedance state. The outputs provide inverted data when they are not in the high-impedance state.

SN54AHCT540 . . . J OR W PACKAGE SN74AHCT540 . . . DB, DGV, DW, N, OR PW PACKAGE (TOP VIEW)



SN54AHCT540 . . . FK PACKAGE (TOP VIEW)



The SN54AHCT540 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AHCT540 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE

	INPUTS	OUTPUT	
OE1	OE2	Α	Y
L	L	L	Н
L	L	Н	L
Н	X	Χ	Z
Х	Н	Χ	Z



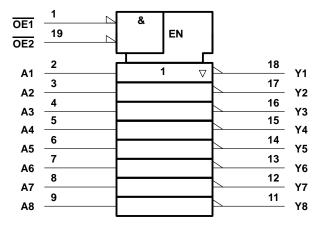
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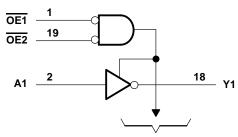
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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



To Seven Other Channels

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, V _I (see Note 1)		–0.5 V to 7 V
Output voltage range, VO (see Note 1)		$0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$)		
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CO}$	c)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})		±25 mA
Continuous current through V _{CC} or GND		±75 mA
Package thermal impedance, θ _{JA} (see Note 2)): DB package	115°C/W
	DGV package	146°C/W
	DW package	97°C/W
	N package	67°C/W
	PW package	128°C/W
Storage temperature range, T _{stg}		–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions (see Note 3)

		SN54AH	CT540	SN74AH	CT540	UNIT
		MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
V _{IL}	Low-level input voltage		0.8		0.8	V
٧ _I	Input voltage	0	5.5	0	5.5	V
Vo	Output voltage	0	VCC	0	VCC	V
ІОН	High-level output current		-8		-8	mA
lOL	Low-level output current		8		8	mA
Δt/Δν	Input transition rise or fall rate		20		20	ns/V
T _A	Operating free-air temperature	- 55	125	-40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vaa	T _A = 25°C			SN54AHCT540		SN74AHCT540		UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	0.1 0.44 ±2.5 ±1 40 1.5	UNII
Vou	I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		4.4		٧
VOH	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8	0.1 0.44 ±2.5 ±1 40	٧
V _{OL}	I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	- ∨
VOL	I _{OL} = 8 mA	4.5 V			0.36		0.44		0.1 0.44 ±2.5 ±1 40	
loz	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5		±2.5	μΑ
lį	V _I = V _{CC} or GND	5.5 V			±0.1		±1		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
ΔI _{CC} †	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5	mA
C _i	$V_I = V_{CC}$ or GND	5 V		2	10				10	pF
Co	$V_O = V_{CC}$ or GND	5 V		4					·	pF

[†] This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

SN54AHCT540, SN74AHCT540 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			MIN	MAX	UNIT												
	(01)	(0011 01)	OAI AGITAIVOE	MIN	TYP	MAX	IVIIIV	IVIAA													
tPLH*	А	Y	C _L = 15 pF		4	6	1	7.5	ns												
^t PHL*		•	OL = 13 pi		4	6	1	7.5	115												
^t PZH*	<u>OE</u>	Y	C _L = 15 pF		5.5	8	1	9	ns												
tPZL*	OE	T	ı	ı	'	1	ľ	ſ	1	ľ	1	1	ı	- CL = 13 βF	OL = 15 pr		5.5	8	1	9	115
^t PHZ*		ŌĒ	Y	C _I = 15 pF		5	8	1	9	ns											
tPLZ*	OE	•	OL = 13 pi		5	8	1	9	115												
^t PLH	А	Y	C _L = 50 pF		6	8.5	1	10	ns												
^t PHL	A	•	CL = 50 pr		6	8.5	1	10	115												
^t PZH	<u>OE</u>	Y	C _L = 50 pF		7.5	11	1	12	ne												
t _{PZL}	OE	Ť	OL = 50 pr		7.5	11	1	12	ns												
^t PHZ	<u>OE</u>	Y	C _L = 50 pF		8	11	1	12	ns												
t _{PLZ}	OE	ſ	OL = 50 pr		8	11	1	12	115												

^{*} On products compliant to MIL-PRF-38535, this parameter is warranted but not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

		TO (OUTPUT)		SN																	
PARAMETER	FROM (INPUT)		LOAD CAPACITANCE	T _A = 25°(5	MIN	MAX	UNIT													
	(01)	(0011 01)	OAI AOITAIVOE	MIN TYP	MAX	IVIIIV	WAA														
^t PLH	А	Y	C _I = 15 pF	4	6	1	7.5	ns													
^t PHL		ı	OL = 13 pi	4	6	1	7.5	115													
^t PZH	ŌĒ	Y	C _L = 15 pF	5.5	8	1	9	ns													
^t PZL	OE		ī	I	ı	ľ	'		1	ſ	ı	I	1	1	- CL = 13 βF	CL = 15 pr	5.5	8	1	9	115
^t PHZ	ŌĒ	Y	C _L = 15 pF	5	8	1	9	20													
t _{PLZ}	OE	ī	CL = 15 pr	5	8	1	9	ns													
^t PLH	А	Y	C _I = 50 pF	6	8.5	1	10	ns													
^t PHL	A	1 CL=	OL = 30 pr	6	8.5	1	10	115													
^t PZH	OE	Y	C _L = 50 pF	7.5	11	1	12	ns													
t _{PZL}	OE		ſ	<u> </u>	T	T .	<u>'</u>		T	r 	ı	ı	<u>'</u>	ı	CL = 50	OL = 50 pr	7.5	11	1	12	115
^t PHZ	ŌĒ	Y	V C: 50 pF	8	11	1	12														
t _{PLZ}	OE .	r	C _L = 50 pF	8	11	1	12	ns													

output-skew characteristics, C_L = 50 pF (see Note 4)

PARAMETER	5004			SN74Al			
	FROM (INPUT)	TO (OUTPUT)	Vcc	T _A = 25°C	MIN	MAX	UNIT
	(01)			MIN MAX	IVIIIV		
^t sk(o)	А	Y	$5~V\pm0.5~V$	1		1	ns

NOTE 4: Skew between any two outputs of the same package switching in the same direction. This parameter is warranted but not production tested



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noise characteristics, $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 5)

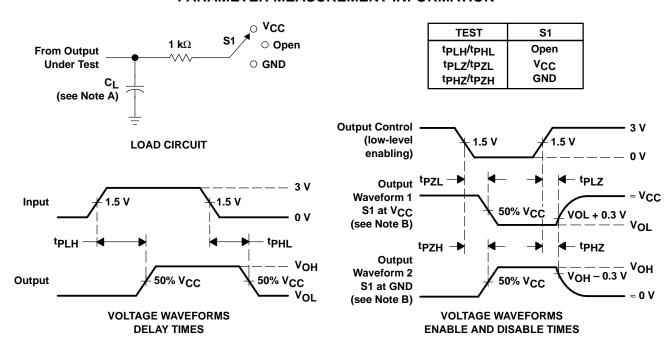
	PARAMETER	SN74AHCT540		UNIT
	PARAINETER	MIN	MAX 0.8	UNIT
V _{IH(D)}	High-level dynamic input voltage	2		V
V _{IL(D)}	Low-level dynamic input voltage		0.8	V

NOTE 5: Characteristics are for surface-mount packages only. These parameters are warranted but not production tested.

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST C	ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	12	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f = 3 \text{ ns}$, $t_f = 3 \text{ ns}$.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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